IBM Docket: BUR920030058US1 SSM&P Docket: 16693

## **Declaration and Power of Attorney for Patent Application**

As a below named inventor, I hereby declare that:

the specification of which (check one)

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: HIGH TOLERANCE TCR BALANCED HIGH CURRENT RESISTOR FOR RF CMOS AND RF SIGE BICMOS APPLICATIONS AND CADENCED BASED HIERARCHICAL PARAMETERIZED CELL DESIGN KIT WITH TUNABLE TCR AND ESD RESISTOR BALLASTING FEATURE

x	is attached hereto.			
	was filed on	as Appli	cation Serial No.	and was amended on
I hereby state amended by an	that I have reviewed and un y amendment referred to abo	derstand the contents of ove.	the above- identified specification,	, including the claims, as
I acknowledge t Code of Federa	the duty to disclose informations. §1.56.	on which is material to the	patentability of this application in a	accordance with Title 37,
certificate liste	foreign priority benefits under ed below and have also identif the application on which prior	ied below any foreign appl	de, §119 of any foreign application( cation for patent or inventor's certi	s) for patent or inventor's ficate having a filing date
Prior	Foreign Application(s):			
Numb	oer Cou	ntry	Day/Month/Year	Priority Claimed
the first paragra of this applicat	of each of the claims of this ap aph of Title 35, United States	oplication is not disclosed in Code, §112, I acknowledge ode of Federal Regulations	y United States application(s) listed I the prior United States application the duty to disclose information ma , §1.56 which occurred between th lication:	in the manner provided by
Prior	U.S. Applications:			
Seria	l No.	Filing Date	Statu	s
like so made ar	ved to be true; and further tha	at these statements were n onment, or both, under Sec	e are true and that all statements in lade with the knowledge that willful tion 1001 of Title 18 of the United Son or any patent issued thereon.	I false statements and the
Richard A. Henk No. 27,465); Ro Redmond, Jr. (F	Trademark Office connected kler, Reg. No. 39,220; Richard bert A. Walsh (Reg. No. 26,51 Reg. No. 18,753); Steven Fisc	therewith: Anthony Cana M. Kotulak (Reg. No. 27,712 6); Christopher A. Hughes hman (Reg. No. 34,594); Le	ents to prosecute this application ar ile, Reg. No. 51,526; Mark F. Chad i); Michael LeStrange (Reg. No. 53,20 (Reg. No. 26,914); John E. Hoel (Re popold Presser, (Reg. No. 19,827); F. 1,972); Leslie S. Szivos (Reg. No. 39,3	urjian (Reg. No. 30,739); 07); William D. Sabo (Reg. g. No. 26,279); Joseph C. rank S. DiGiglio (Reg. No.

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## **Declaration and Power of Attorney for Patent Application**

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